





Distributed control system for the BM@N experiment

Alushta-2025



Association of Young

SCIENTISTS AND SPECIALISTS OF JINR

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on behalf of Slow Control group:

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BM@N Experiment





BM@N building in NICA complex

BM@N experiential hall:





BM@N subsystems

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What is Slow Control?



- Monitoring of the experimental hardware;
- Centralized control of the Slow Control equipment (LV, HV, gas flow etc.);
- Archiving historical Slow Control data;
- Alarm system.

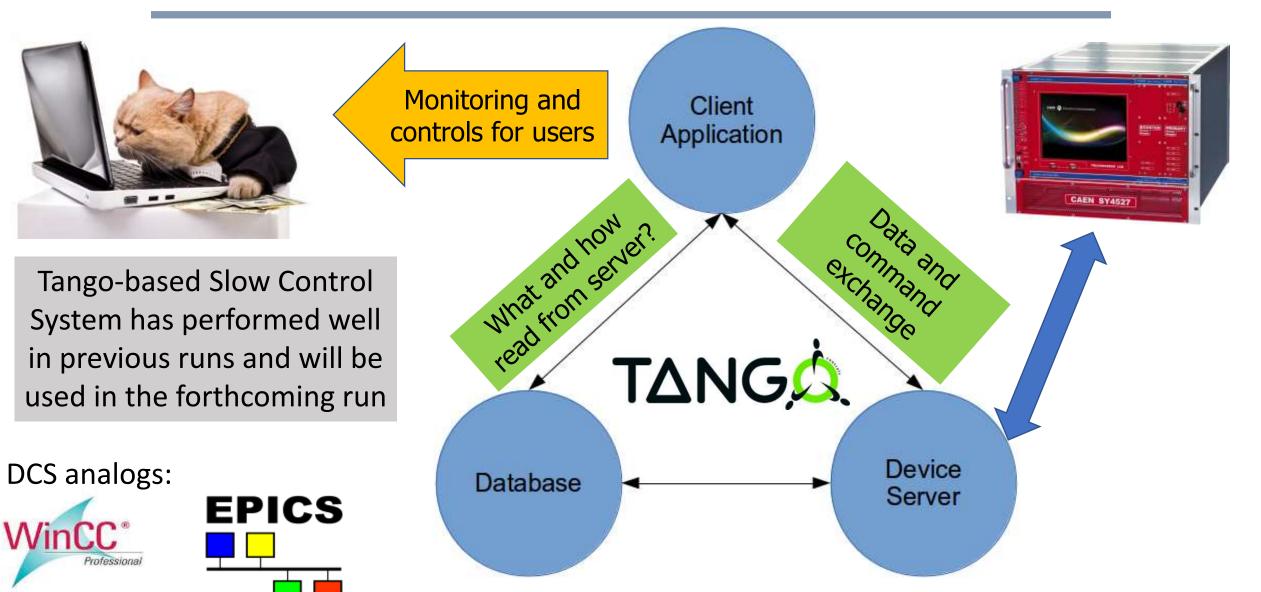
Not a Slow Control:

- Main data stream (data taking);
- Event builder (reconstruction)/event display;
- Data quality;
- Run control.

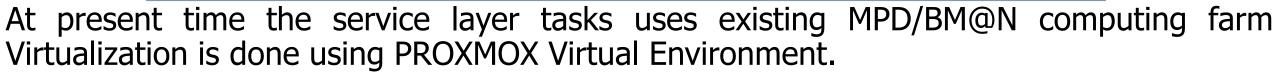
What is Slow Control?

BM@N





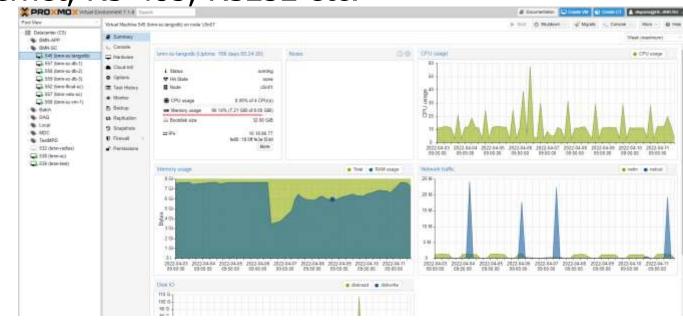
Infrastructure – computing, devices, interfaces



All centralized services are running on dedicated VM's

Front-end layer includes a wide variety of devices which are uses different buses and protocols, such as PXI, Ethernet, RS-485, RS232 etc.



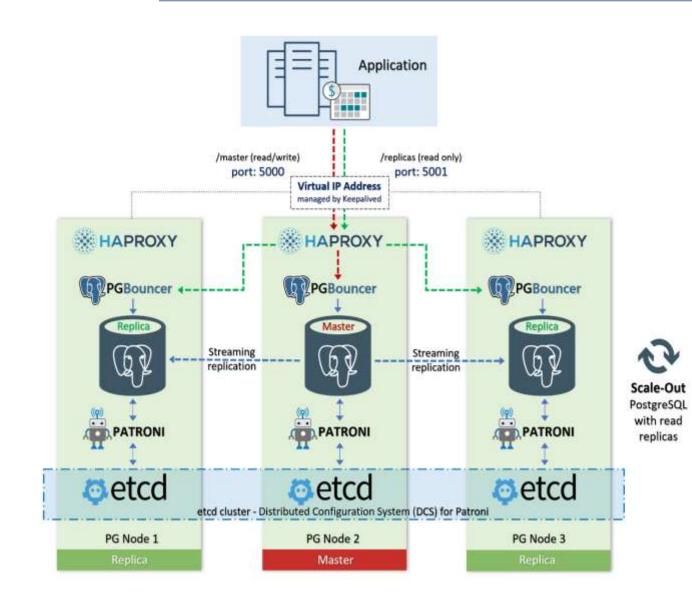




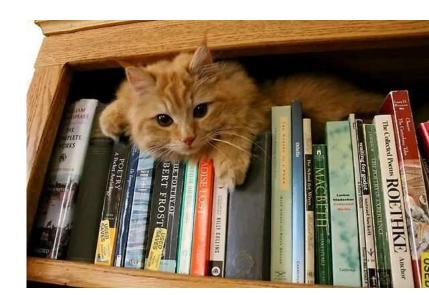
PGBouncer

PG Node N





BM@N





Data visualization



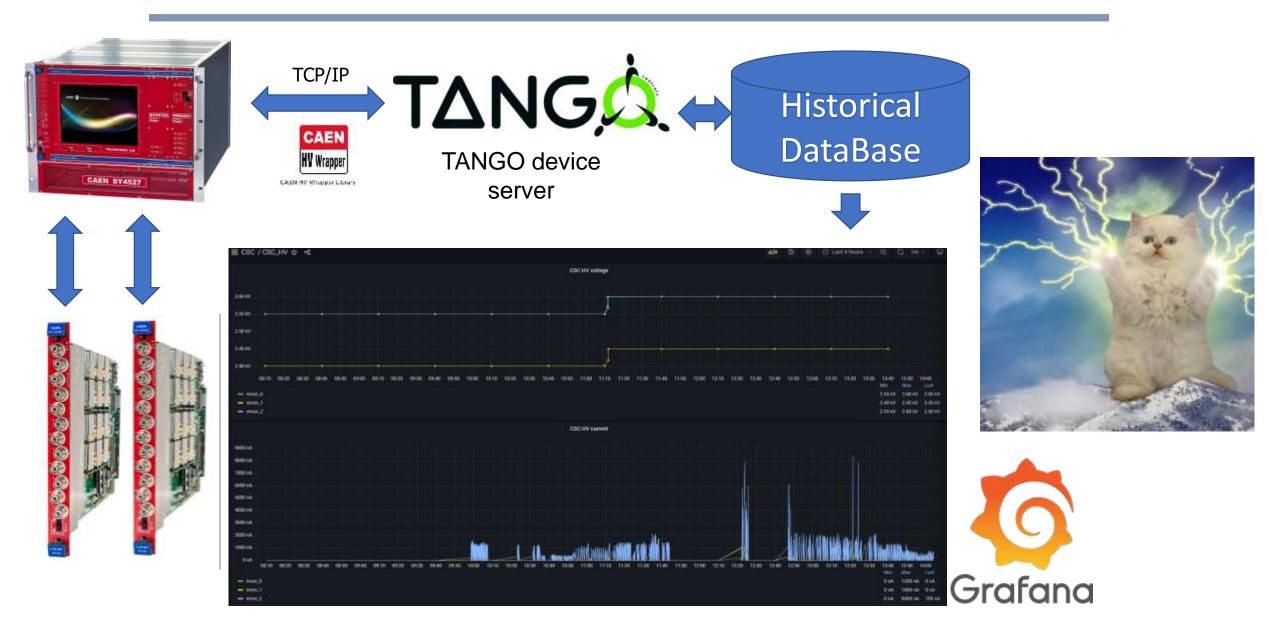


Grafana is a free software data visualization system focused on IT monitoring systems data. It is implemented as a "dashboard" style web application with charts, graphs, tables, alerts.

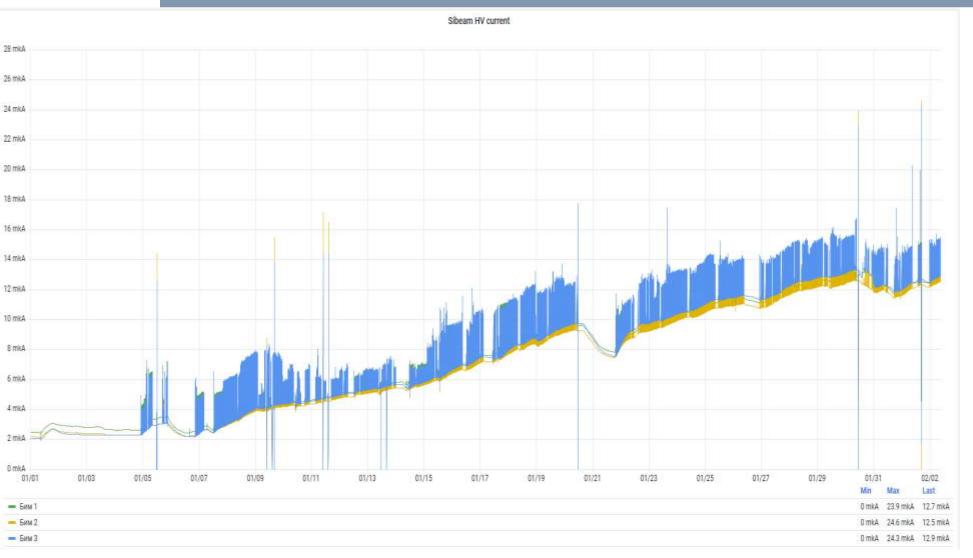


BMON HV system of FSD, GEM, BT

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BMON HV system of FSD, GEM, BT

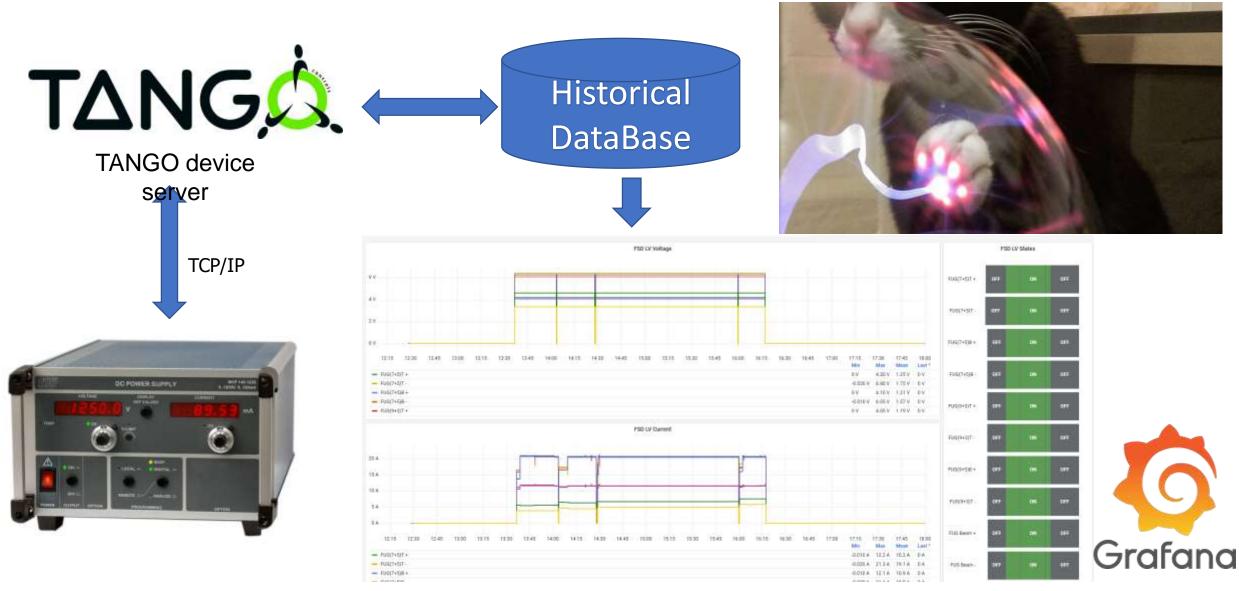


The average value of the dark current at the beginning of the session is $0.761 \mu A$, measured at a temperature of +22.5°C; the average value of the dark current at the end of the session, for a reason radiation damage, is 12.7 μA ,

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The change in detector currents at three beam tracker stations during the 2022-2023 session is shown.







FSD FEE temperature











BM@N



Increasing dark currents of silicon detectors 35 mkA 30 mkA

25 mkA 20 mkA 15 mkA

10 mkā

0 mkA

0410 0415

04/20 04/25

54:55

11.8-15

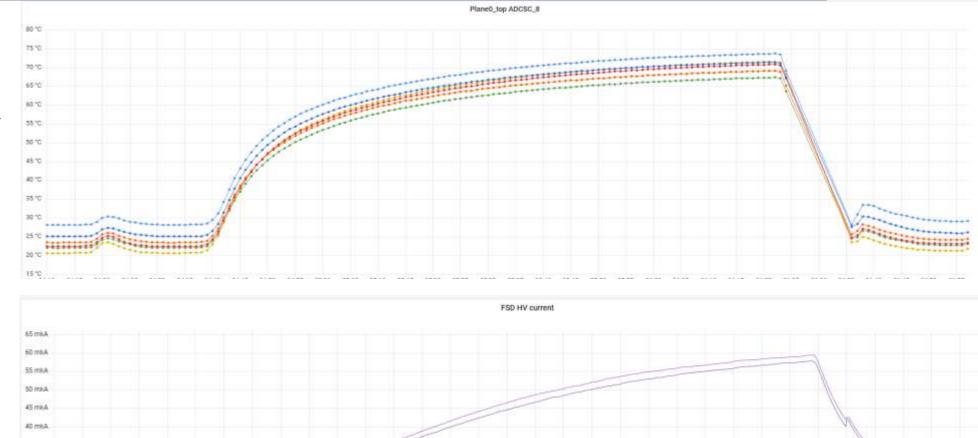
04:55

0510

1515

05/20 05/25

04:55



0545 0550 0555 0400 0405 0410 0615 0420

06:25 06:30

06:40

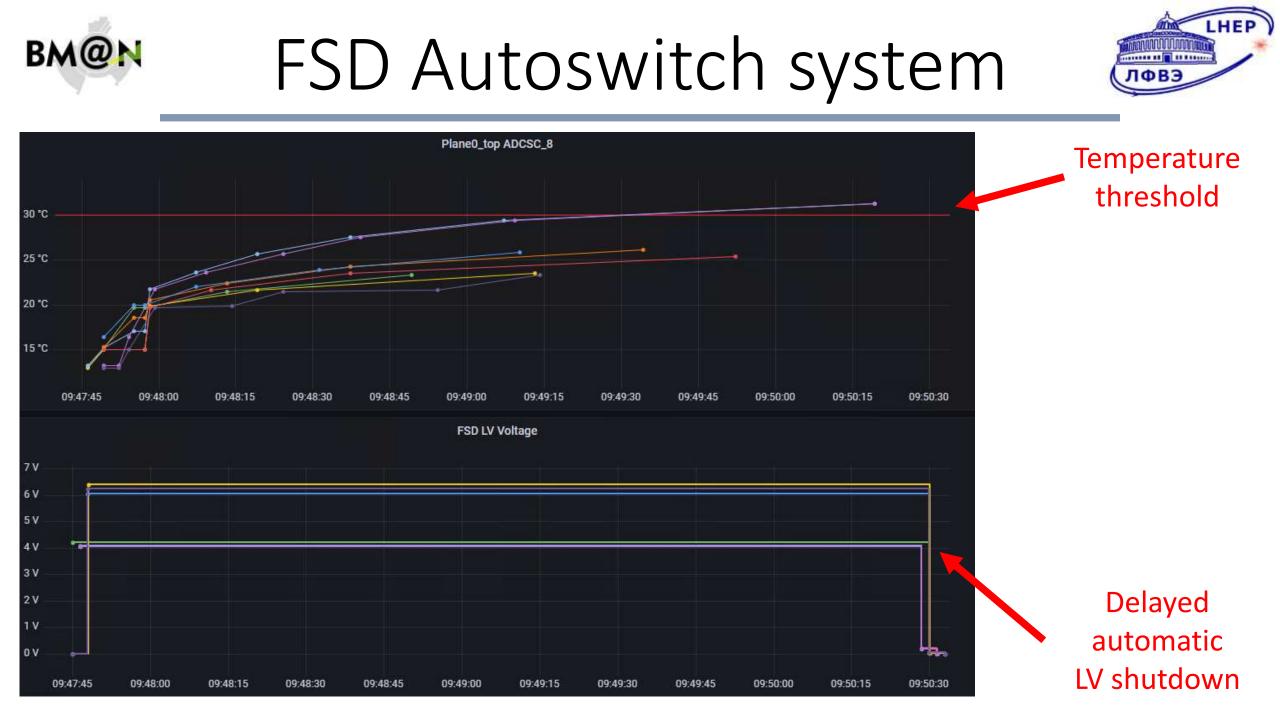
06/35

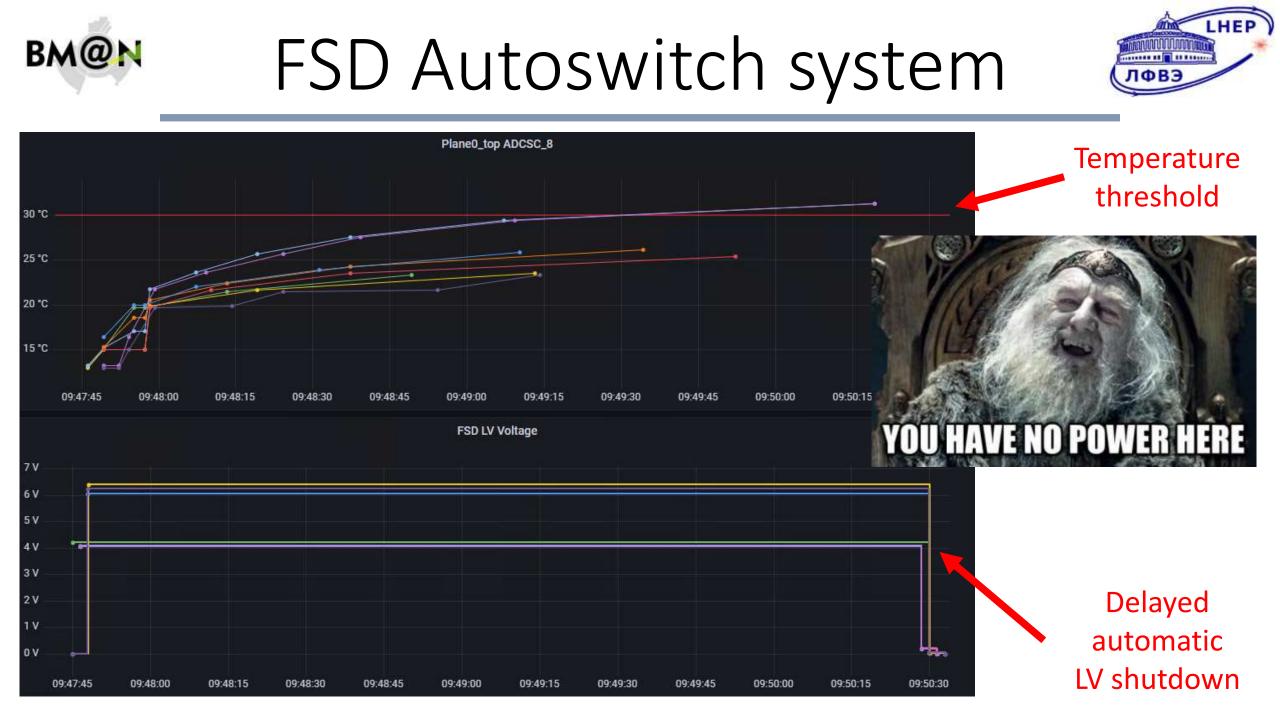
06.45

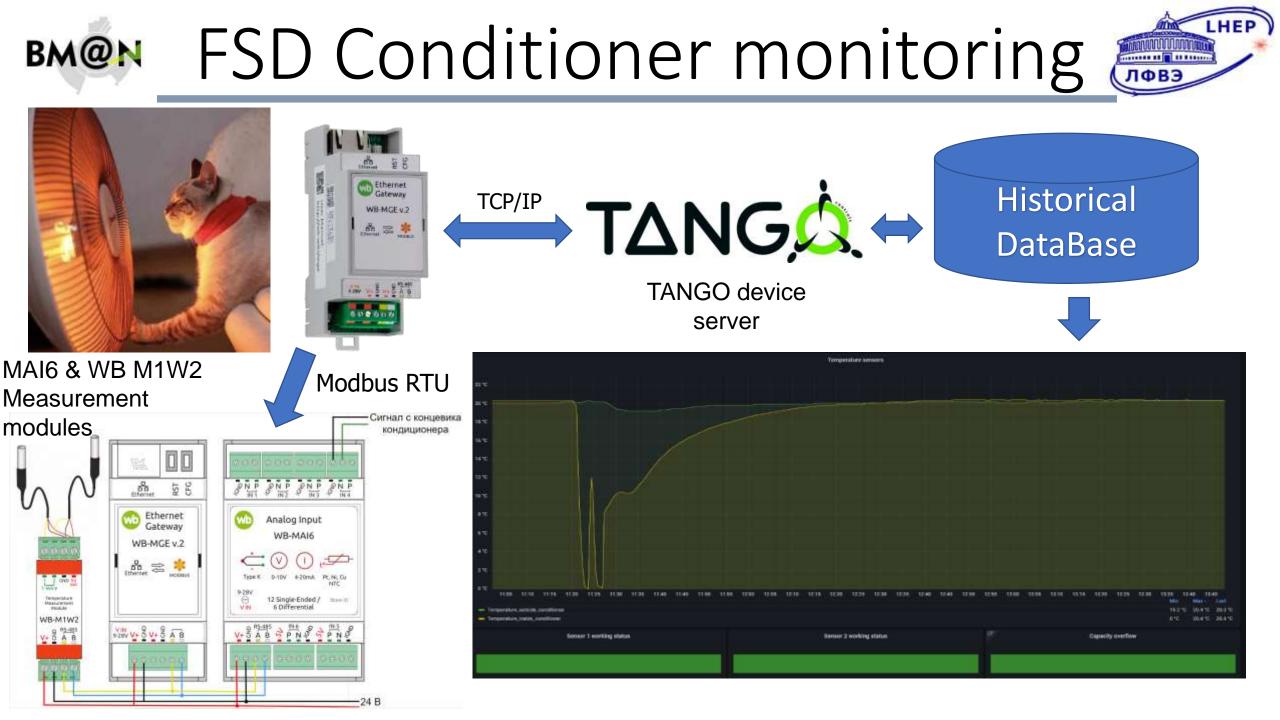
05.40

05:25

05:30







Conclusions

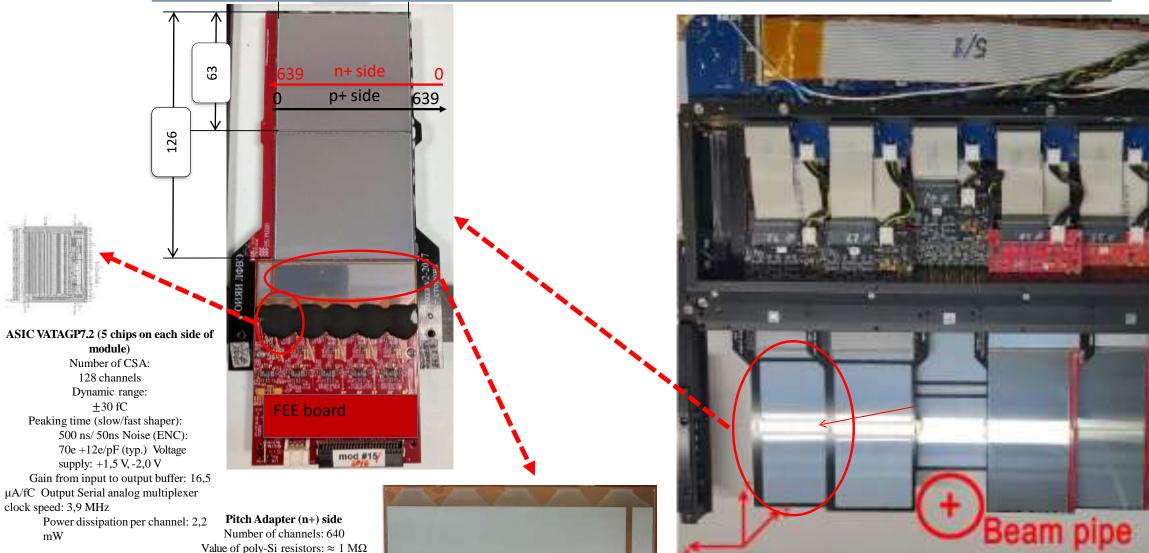
BM@N





Thank You for attention!

LHEP BM@N FSD___Forward Silicon Detector ЛФВЭ



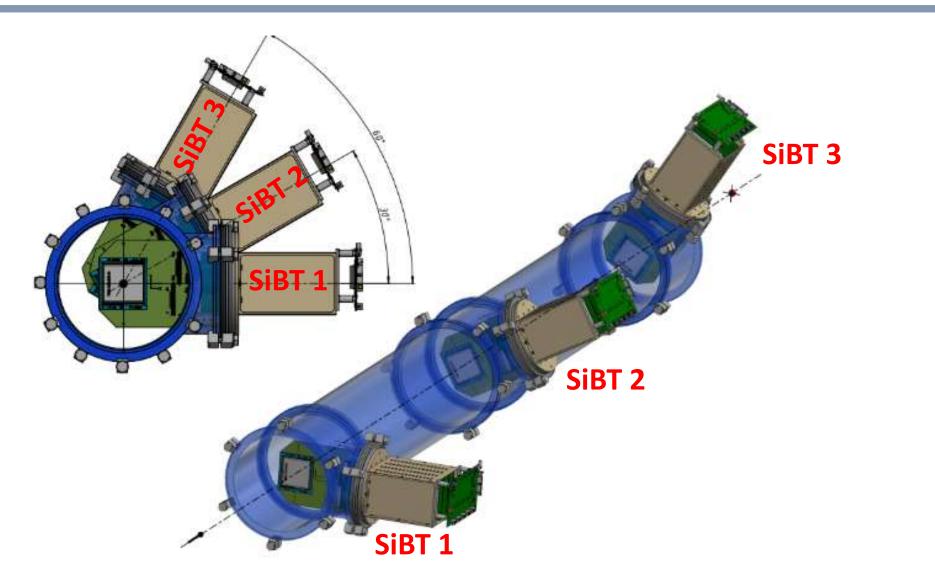
Value of integrated capacitors: $\approx 120 \text{ pF}$ Capacitor working voltage: 100 V Capacitor breakdown voltage: >150 V

Manufactured by ZNTC (Zelenograd)

Coordinate plane from double side Si-modules

7/12





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